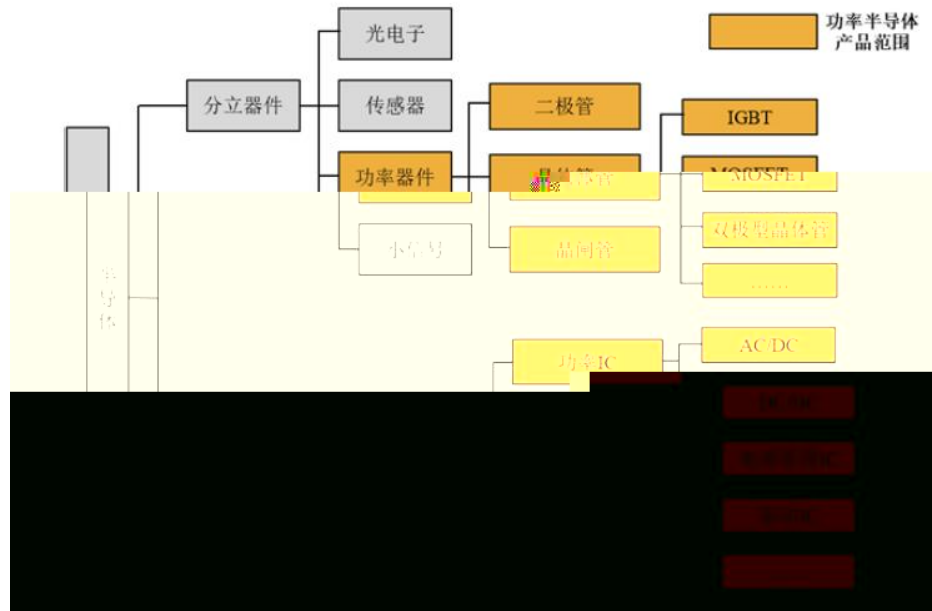


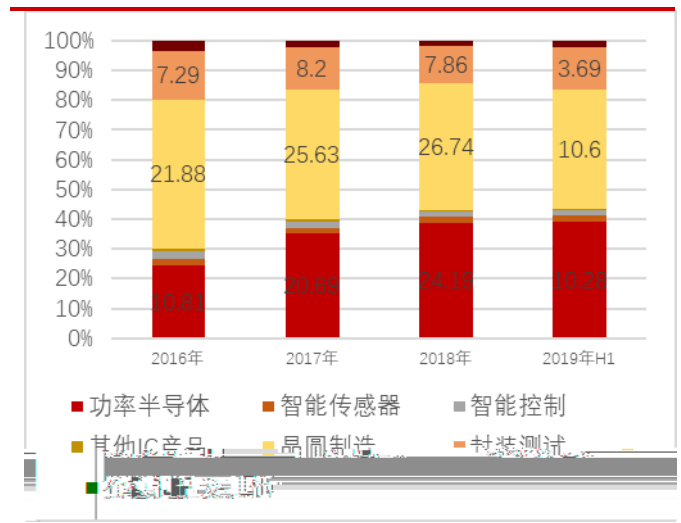
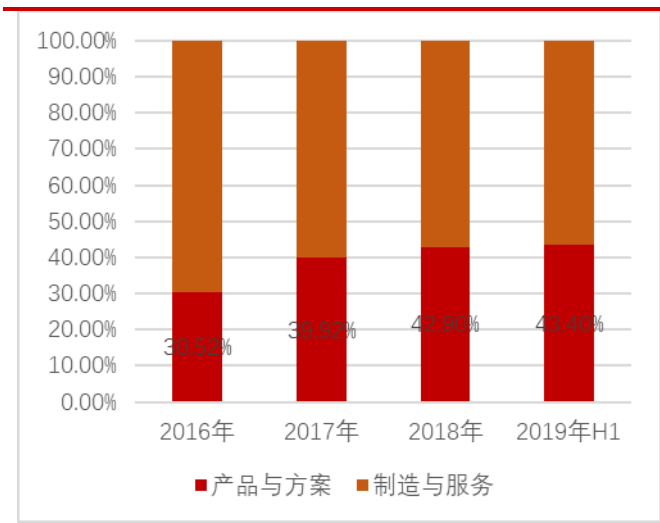




功率半导体产品范围示意图



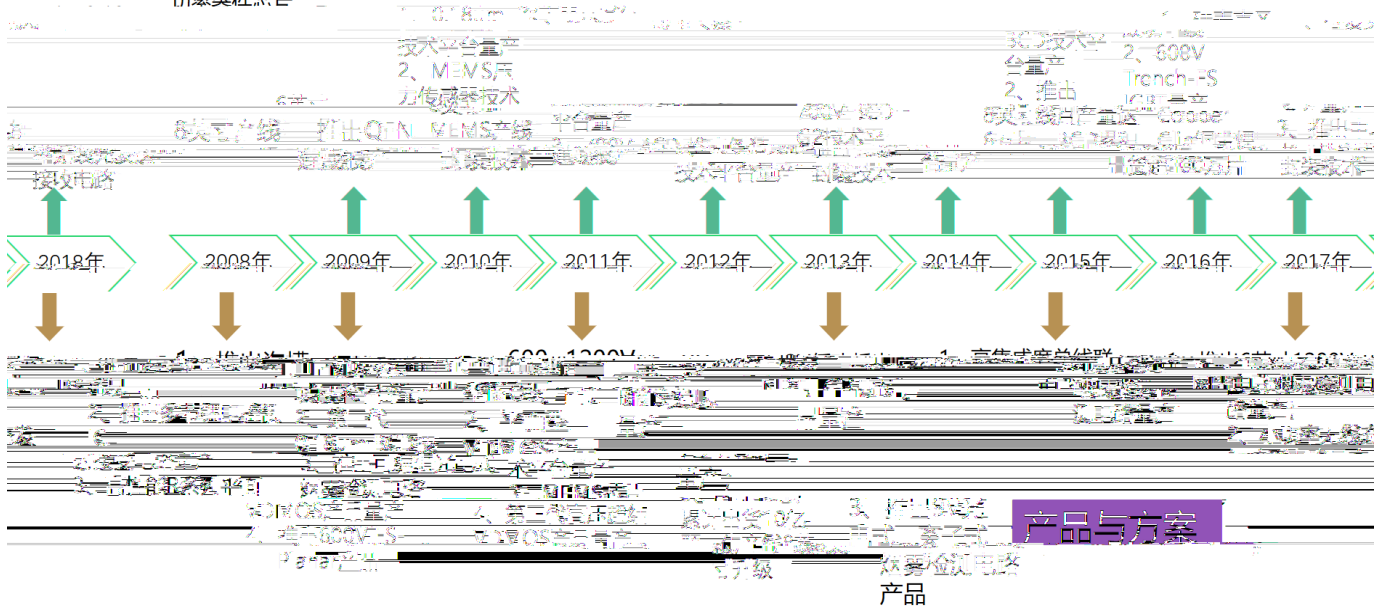




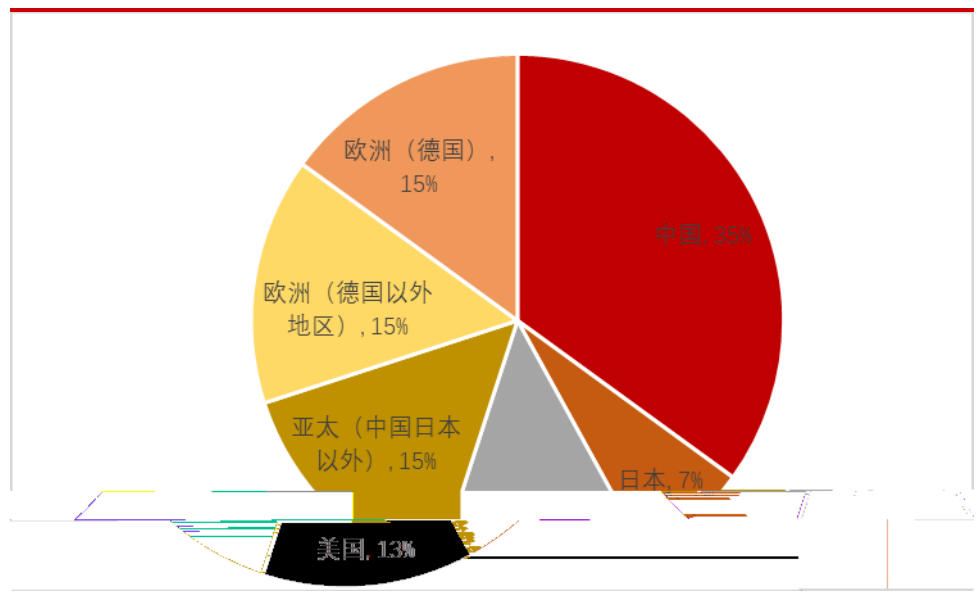
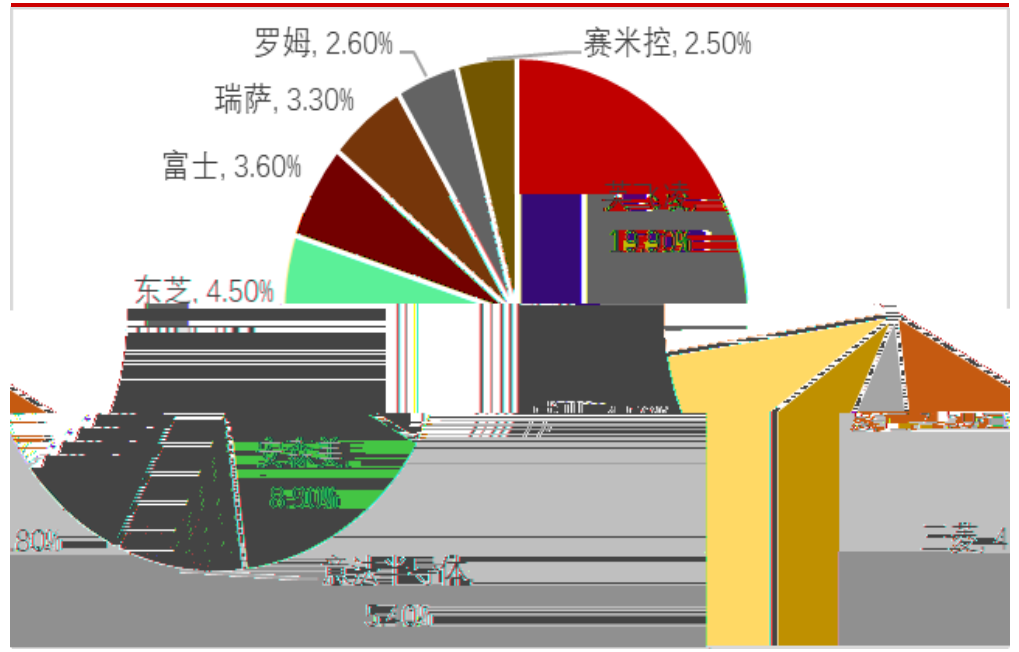
1、第一片6英寸600V耗尽

制造与服务

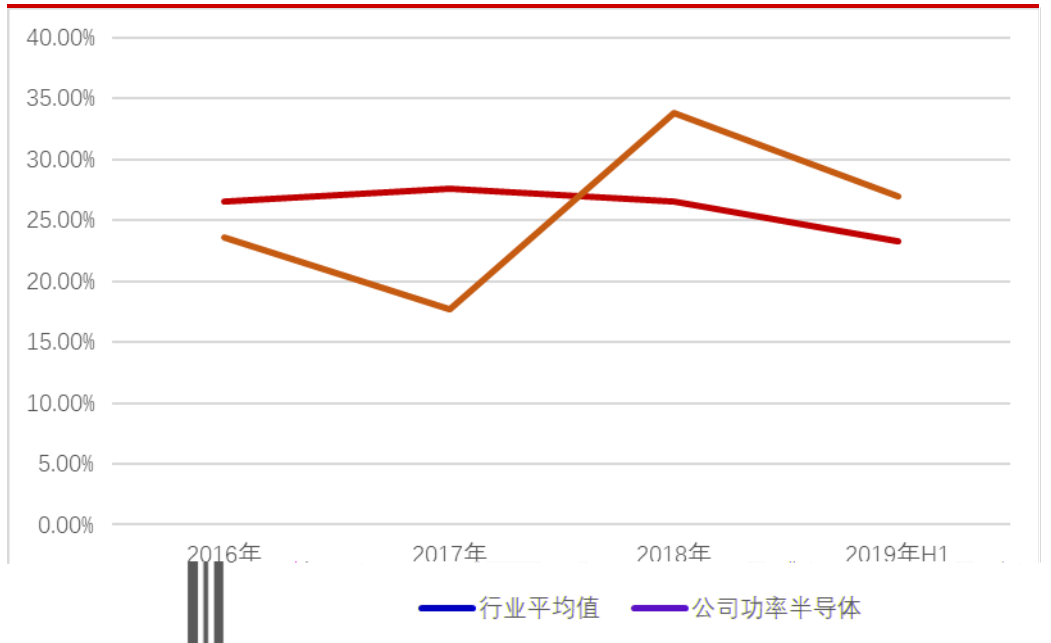
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功率器件技术

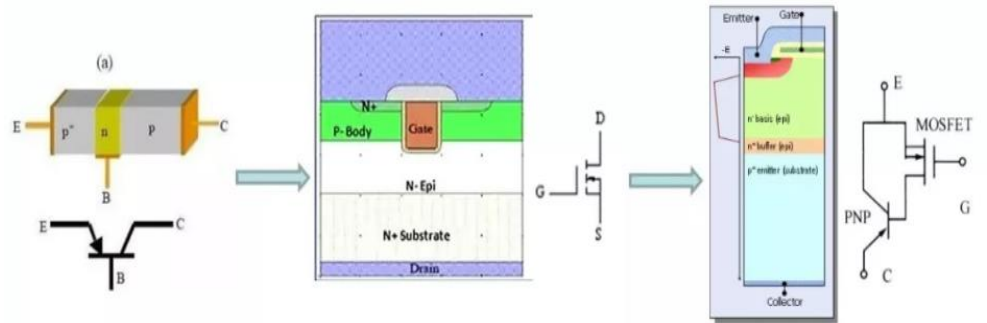








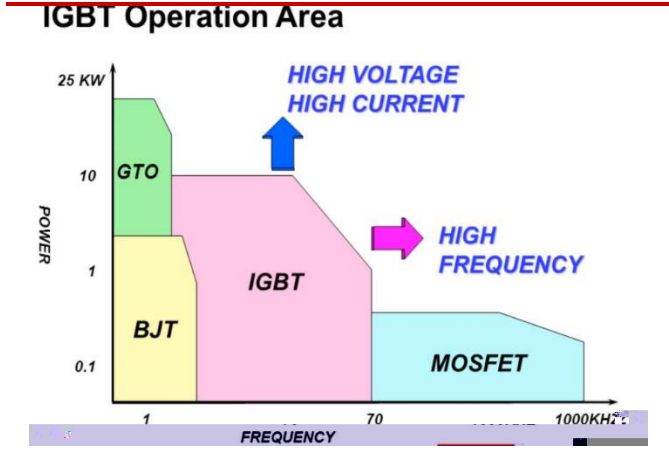
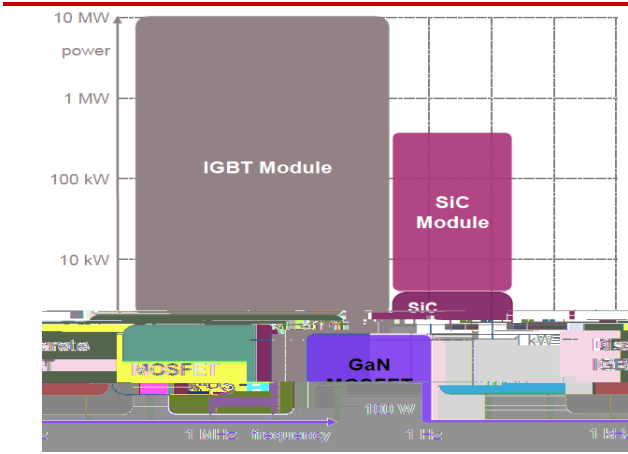




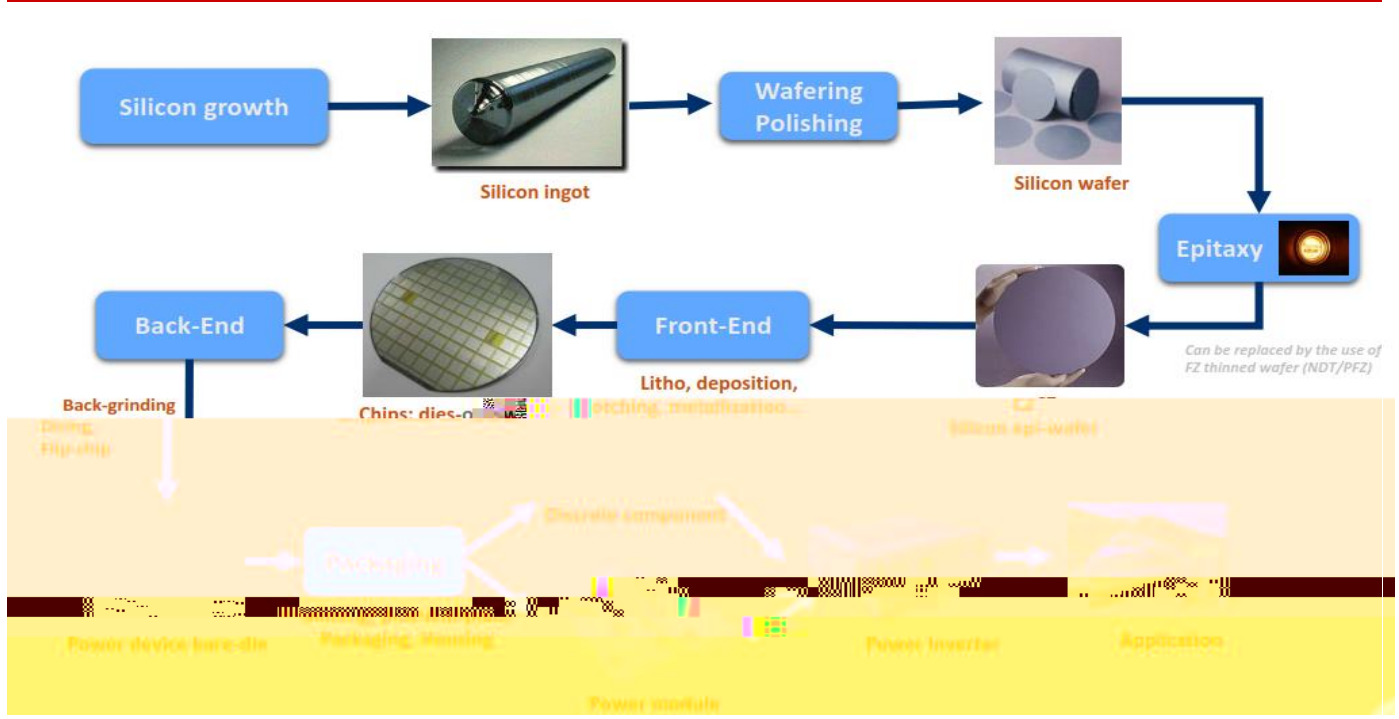
双极性三极管

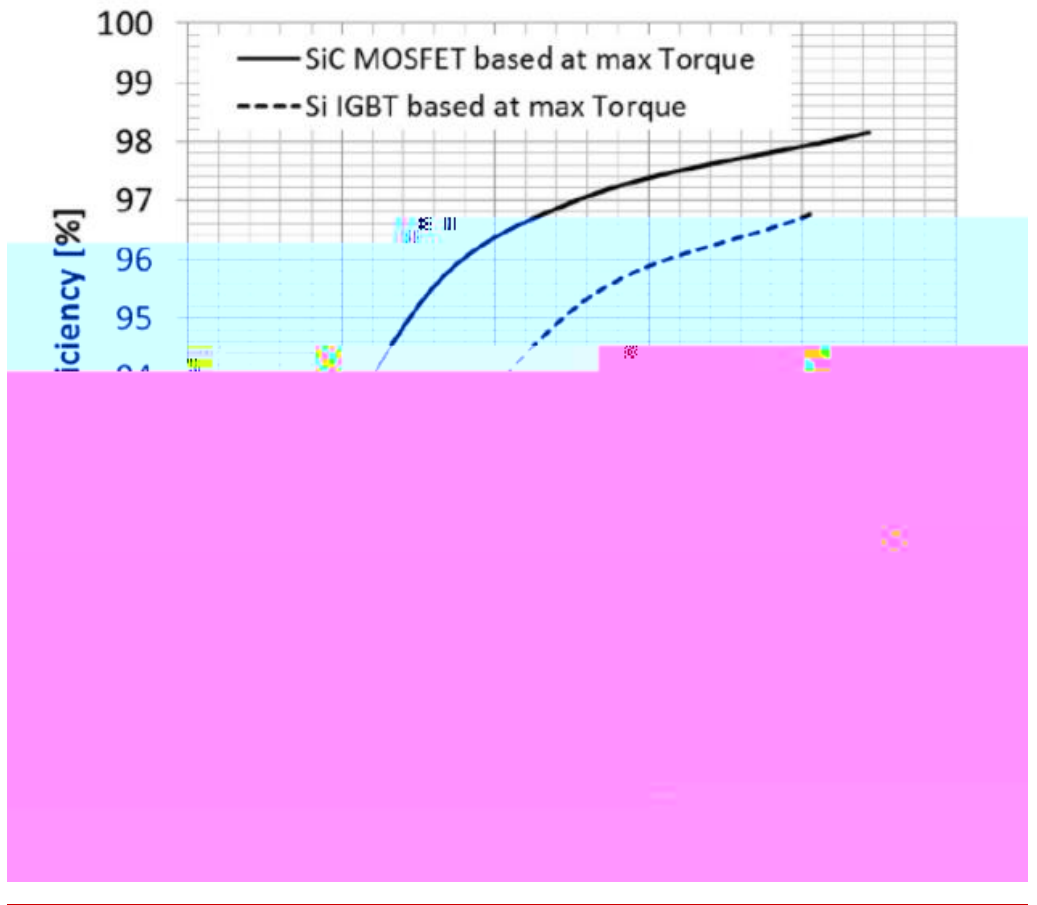
MOSFET

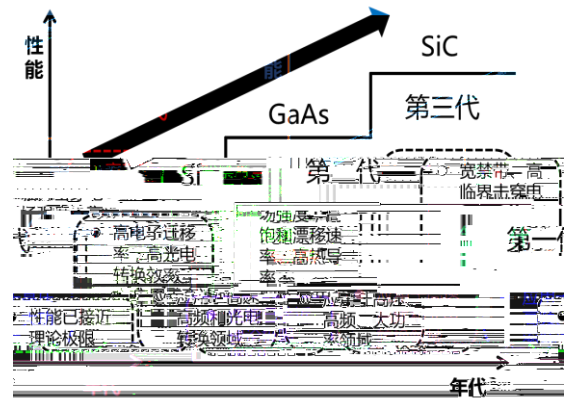
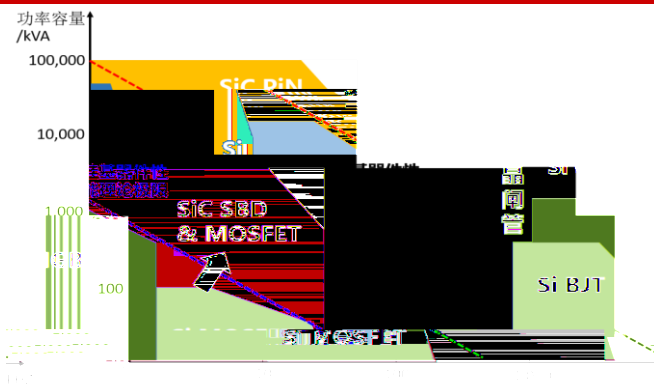
IGBT



Trench

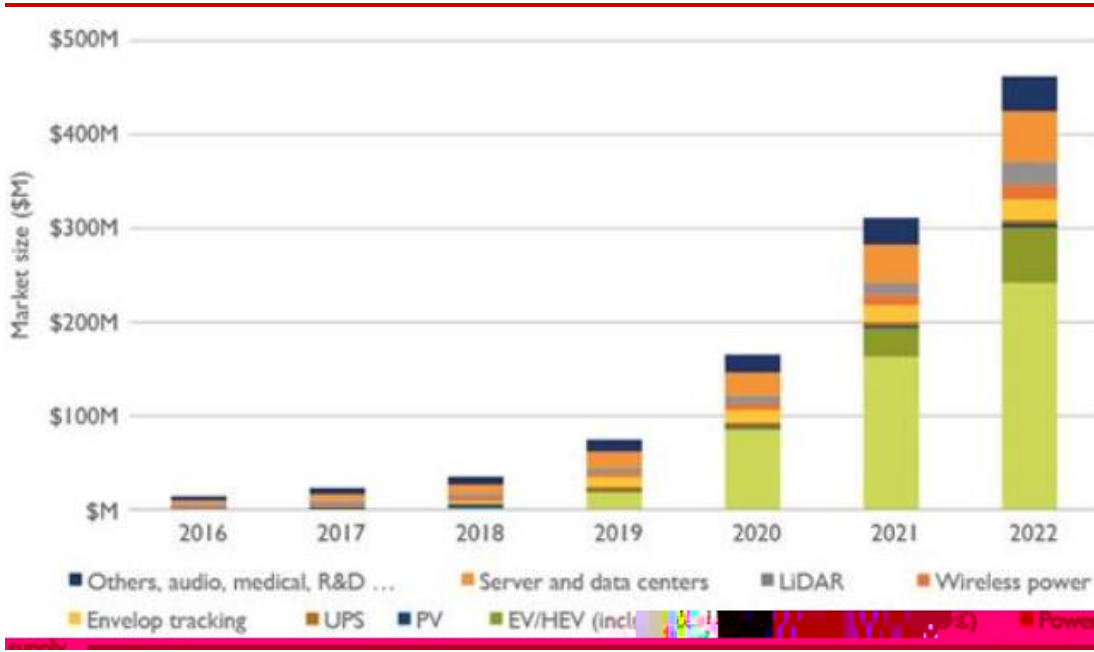






SiC power device market size split by application





TM
